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THIRD SERIES, VOLUME 57, NUMBER 19 ***CONTENTS*** **15 MAY 1998-I**

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Orthogonal polynomial projectors for the projector augmented wave method of electronic structure calculations 11 827
N. A. W. Holzwarth, G. E. Matthews, A. R. Tackett, and R. B. Dunning

Real-space renormalization-group study of the Hubbard model: A modified scheme 11 831
Bibhas Bhattacharyya and Shreekantha Sil

Gaussian-basis LDA and GGA calculations for alkali-metal equations of state 11 834
John E. Jaffe, Zijing Lin, and Anthony C. Hess

Mott-Peierls transition in the extended Peierls-Hubbard model 11 838
Eric Jeckelmann

Anderson transitions in three-dimensional disordered systems with randomly varying magnetic flux 11 842
Tohru Kawarabayashi, Bernhard Kramer, and Tomi Ohtsuki

Temperature-dependent core-level x-ray photoemission spectroscopy of the organic conductors $(MeCl\text{-}DCNQI)_2Cu$, $(MeBr\text{-}DCNQI)_2Cu$, and $(DI\text{-}DCNQI)_2Cu$ 11 846
O. Akaki, A. Chainani, T. Takahashi, Y. Kashimura, and R. Kato

Hall effect in crystalline Ni-Fe-Cr alloys showing resistivity minima 11 850
S. Chakraborty and A. K. Majumdar

Violation of Kohler's rule by the magnetoresistance of a quasi-two-dimensional organic metal 11 854
Ross H. McKenzie, J. S. Qualls, S. Y. Han, and J. S. Brooks

Variable-range-hopping conduction and dielectric relaxation in disordered $Sr_{0.97}(Ti_{1-x}Fe_x)O_{3-\delta}$ 11 858
Chen Ang, J. R. Jurado, Zhi Yu, M. T. Colomer, J. R. Frade, and J. L. Baptista

Ensemble properties in quantum steady-state nonequilibrium theories 11 862
Carsten Heide and Nikolai F. Schwabe

Semiconductors I: bulk

Acceleration fluctuation scheme for diffusion noise sources within a generalized impedance field method 11 866
P. Shiktorov, E. Starikov, V. Gružinskis, L. Reggiani, T. González, J. Mateos, D. Pardo, and L. Varani

Angular dependence of impurity scattering in nonparabolic semiconductors 11 870
A. Dutta, P. S. Mallick, and D. Mukhopadhyay

High-magnetic-field effects on the terahertz mobility of hot electrons in *n*-type InSb 11 872
E. W. S. Caetano, E. A. Mendes, V. N. Freire, J. A. P. da Costa, and X. L. Lei

Transverse electric-field-induced magnetophonon resonance in *n*-type germanium 11 875
S. C. Lee, Y. B. Kang, G. Y. Hu, J. Y. Ryu, and S. D. Choi

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Suppression of Ostwald ripening in $In_{0.5}Ga_{0.5}As$ quantum dots on a vicinal (100) substrate 11 879
Byung Don Min, Yong Kim, Eun Kyu Kim, Suk-Ki Min, and Mann Jang Park

Surface structure of cesium adsorption on the Si(001) 2×1 surface 11 883
H. Hamamatsu, H. W. Yeom, T. Yokoyama, T. Kayama, and T. Ohta

Excited Wannier-Stark states in the optical absorption of a superlattice in an electric field 11 887
S. Glutsch and F. Bechstedt

(Continued)

0163-1829(19980515)57:19;1-0

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

Transport through an interacting quantum dot coupled to two superconducting leads 11 891
Kicheon Kang
Change of Hall conductance induced by band crossing 11 895
Ming-Yi Lee, Ming-Che Chang, and Tzay-Ming Hong
Tunneling spectrum of a strongly driven double-well diode 11 899
Mathias Wagner
Discontinuity in the phase evolution of electron transport in a quantum channel with attached quantum dots 11 903
Hongqi Xu and Weidong Sheng
Magnetoconductance of a quantum wire with several antidots: A transfer-matrix study 11 907
C. C. Wan, Tiago De Jesus, and Hong Guo
Spin-orbit interaction in a two-dimensional electron gas in a InAs/AlSb quantum well with gate-controlled electron density 11 911
J. P. Heida, B. J. van Wees, J. J. Kuipers, T. M. Klapwijk, and G. Borghs
Resistance resonance induced by electron-hole hybridization in a strongly coupled InAs/GaSb/AlSb heterostructure 11 915
L. J. Cooper, N. K. Patel, V. Drouot, E. H. Linfield, D. A. Ritchie, and M. Pepper
Raman study of the nitrided GaAs thin layers 11 919
Eui Kwan Koh, Young Ju Park, Eun Kyu Kim, Suk-Ki Min, and Sung Ho Choh

Surface physics, low-dimensional systems, and related topics

Edge-driven transition in the surface structure of nanoscale silicon 11 923
Sohrab Ismail-Beigi and Tomás Arias
Surface flatness and structure of the bc-cleaved plane of spin-Peierls material $CuGeO_3$ 11 927
I. Tsukada, N. Koide, Y. Sasago, and K. Uchinokura
Adsorption of water on MgO(100): A singular behavior 11 931
C. Girardet, P. N. M. Hoang, A. Marmier, and S. Picaud
In-plane magnetic anisotropy of bcc Co on GaAs(001) 11 935
Y. Z. Wu, H. F. Ding, C. Jing, D. Wu, G. L. Liu, V. Gordon, G. S. Dong, X. F. Jin, S. Zhu, and K. Sun
Charge transfer and doping-dependent hybridization of C_{60} on noble metals 11 939
B. W. Hoogenboom, R. Hesper, L. H. Tjeng, and G. A. Sawatzky
Electronic-momentum distribution in deformed sodium clusters 11 943
A. Rigo, M. Casas, F. Garcias, E. Moya de Guerra, and P. Sarriguren
Quasiclassical approach to the weak levitation of extended states in the quantum Hall effect 11 947
M. M. Fogler
Femtosecond dynamics of adsorbate charge-transfer processes as probed by high-resolution core-level spectroscopy 11 951
C. Keller, M. Stichler, G. Comelli, F. Esch, S. Lizzit, D. Menzel, and W. Wurth

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Charge-transfer metal-insulator transitions in the spin-$\frac{1}{2}$ Falicov-Kimball model 11 955
Woonki Chung and J. K. Freericks
First-order corrections to random-phase approximation GW calculations in silicon and diamond 11 962
R. T. M. Ummels, P. A. Bobbert, and W. van Haeringen
Multiple-excited-state absorption of V^{2+} in low-field crystals: An *ab initio* model-potential embedded-cluster study 11 974
Sara López-Moraza, Luis Seijo, and Zoila Barandiarán

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

Quantum Monte Carlo study of hole binding and pairing correlations in the three-band Hubbard model 11 980
M. Guerrero, J. E. Gubernatis, and Shiwei Zhang
Interplay between Hund coupling and Hubbard interaction in Sr_2RuO_4 ..... 11 989
Mario Cuoco, Canio Noce, and Alfonso Romano
Density-functional crystal orbital study on the structures and energetics of polyacetylene isomers 11 994
So Hirata, Hajime Torii, and Mitsuo Tasumi
Potential role of silanones in the photoluminescence-excitation, visible-photoluminescence-emission, and infrared spectra of porous silicon 12 002
James L. Gole and David A. Dixon
Total energy differences between SiC polytypes revisited 12 017
Sukit Limpijumnong and Walter R. L. Lambrecht
Systematic study of the electronic state in θ-type BEDT-TTF organic conductors by changing the electronic correlation 12 023
Hatsumi Mori, Shoji Tanaka, and Takehiko Mori
Electronic structure of CeSe probed by resonant photoemission spectroscopy: A test case for the single-impurity Anderson Hamiltonian 12 030
G. Chiaia, L. Duò, O. Tjernberg, M. Göthelid, M. Björkqvist, H. Kumigashira, S.-H. Yang, T. Takahashi, T. Suzuki, and I. Lindau
Electrical transport properties of stoichiometric YbP single crystal 12 036
D. X. Li, K. Sumiyama, K. Suzuki, A. Oyamada, K. Hashi, and T. Suzuki
Simple treatment of the metal-insulator transition: Effects of degeneracy, temperature, and applied magnetic field 12 041
Andrzej Klejnberg and Jozef Spałek
Local-field correction for the ferromagnetic electron gas 12 056
Jener J. S. Brito
Resonant electron-exchange excitations in transition-metal oxides 12 069
B. Fromme, M. Möller, C. Bethke, U. Brunokowski, and E. Kisker
Three-point bounds and other estimates for strongly nonlinear composites 12 077
P. Ponte Castañeda
Dissipation of core-hole momentum by phonons in soft-x-ray radiation processes from valence band to core level of wide-gap insulators 12 084
Tatsuya Minami and Keiichiro Nasu
Photoluminescence studies of Sm^{2+} in the stimulable phosphor SrS:Eu,Sm 12 094
Lawrence H. Robins and J. Ari Tuchman
Multichannel impurity scattering in a Tomonaga-Luttinger liquid 12 104
Yu-Liang Liu
Electron distribution in MgO probed by x-ray emission 12 111
P. Jonnard, F. Vergand, C. Bonnelle, E. Orgaz, and M. Gupta
Correlation effects in the quasi-one-dimensional charged Bose condensate 12 119
A. Gold and L. Calmels
Impurity bands in photonic insulators 12 127
N. Stefanou and A. Modinos
Ternary transition-metal aluminide alloy formation: The BiF_3 structure 12 134
R. E. Watson, M. Weinert, and M. Alatalo

Semiconductors I: bulk

Diffusion quantum Monte Carlo calculations of the excited states of silicon 12 140
A. J. Williamson, Randolph Q. Hood, R. J. Needs, and G. Rajagopal
Stochastic model of plasma waves for a simple band structure in semiconductors 12 145
M. Zakari

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

Neutral-donor–bound-exciton complexes in ZnO crystals 12 151
D. C. Reynolds, D. C. Look, B. Jogai, C. W. Litton, T. C. Collins, W. Harsch, and G. Cantwell
Resonant and nonresonant polarons in bulk InSb 12 156
P. Pfeffer
Chlorine-impurity-related defects in ZnSe 12 164
S. Pöykkö, M. J. Puska, and R. M. Nieminen
DX-center transformation of Te donors in GaSb under hydrostatic pressure 12 169
H. Navarro-Contreras, F. de Anda-Salazar, Leon Hsu, and E. E. Haller
Nitrogen-impurity–native-defect complexes in ZnSe 12 174
S. Pöykkö, M. J. Puska, and R. M. Nieminen
Band-gap states of Ti, V, and Cr in 4*H*-SiC: Identification and characterization by elemental transmutation of radioactive isotopes 12 181
Norbert Achtziger and Wolfgang Witthuhn
Raman-scattering study of photoexcited plasma in semiconducting and semi-insulating InP 12 197
R. Cuscó, J. Ibáñez, and L. Artús
Ultrafast charge recombination in undoped amorphous hydrogenated silicon 12 207
Ilya A. Shkrob and Robert A. Crowell
Electron momentum distributions in elemental semiconductors probed by positrons 12 219
Z. Tang, M. Hasegawa, T. Chiba, M. Saito, H. Sumiya, Y. Kawazoe, and S. Yamaguchi
Phonon conductivity in As-, Sb-, and P-doped Ge for intermediate donor concentration 12 229
M. K. Roy and B. K. Deb
Calculation of vibrational lifetimes in amorphous silicon using molecular dynamics simulations 12 234
S. R. Bickham and J. L. Feldman
Giant magnetoresistance in zero-band-gap $Hg_{1-x}Cd_xTe$ 12 239
Tineke Thio, S. A. Solin, J. W. Bennett, D. R. Hines, M. Kawano, N. Oda, and M. Sano

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Electronic and optical properties of laterally composition-modulated $Al_xIn_{1-x}As$, $Ga_xIn_{1-x}P$, and $Ga_xIn_{1-x}As$ alloys 12 245
Yong Zhang and A. Mascarenhas
Influence of stress and defects on the silicon-terminated SiC(001) surface structure 12 255
Alessandra Catellani, Giulia Galli, François Gygi, and Fabio Pellacini
Vertical correlations and anticorrelations in multisheet arrays of two-dimensional islands 12 262
V. A. Shchukin, D. Bimberg, V. G. Malyshkin, and N. N. Ledentsov
Effects of interfacial charges on semiconductor films 12 275
A. M. Alencar, R. N. Costa Filho, V. N. Freire, and G. A. Farias
Pair-tunneling states in semiconductor quantum dots: Ground-state behavior in a magnetic field 12 281
Ernestine Lee, Aaron Puzder, M. Y. Chou, T. Uzer, and David Farrelly
Anharmonic decay of confined optical phonons in quantum dots 12 285
Xin-Qi Li and Yasuhiko Arakawa
Exciton fine structure in CdSe nanoclusters 12 291
K. Leung, S. Pokrant, and K. B. Whaley
Non-Abelian geometric phases and conductance of spin-$\frac{3}{2}$ holes 12 302
Daniel P. Arovas and Yuli Lyanda-Geller
Classical and quantum dynamics of electrons in open equilateral triangular billiards 12 306
L. Christensson, H. Linke, P. Omling, P. E. Lindelof, I. V. Zozoulenko, and K.-F. Berggren
Si intralayers at GaAs/AlAs and GaAs/GaAs junctions: Polar versus nonpolar interfaces 12 314
M. Moreno, H. Yang, M. Höricke, M. Alonso, J. A. Martín-Gago, R. Hey, K. Horn, J. L. Sacedón, and K. H. Ploog

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

Andreev reflection in the fractional quantum Hall effect 12 324
Nancy P. Sandler, Claudio de C. Chamon, and Eduardo Fradkin
Skyrmions in arbitrarily polarized quantum Hall states 12 333
Sudhansu S. Mandal and V. Ravishankar
Electron-electron interaction effect on the conductivity and the Hall conductivity of weakly disordered electron systems 12 338
Michael Reizer
Optical-phonon-induced frictional drag in coupled two-dimensional electron gases 12 345
Ben Yu-Kuang Hu
Edge-induced modification of tunnel mixing and resistance resonance in double-quantum-well strips 12 350
O. E. Raichev and F. T. Vasko
$1/f$ noise in polycrystalline silicon thin films 12 360
Laurence Michelutti
Size dependence of exciton-exciton scattering in semiconductor quantum wires 12 364
W. Braun, M. Bayer, A. Forchel, O. M. Schmitt, L. Bányai, H. Haug, and A. I. Filin
Femtosecond relaxation kinetics of highly excited electronic wave packets in semiconductors 12 369
K. El Sayed, J. A. Kenrow, and C. J. Stanton
Effect of lateral confinement on valence-band mixing and polarization anisotropy in quantum wires 12 378
F. Vouilloz, D. Y. Oberli, M.-A. Dupertuis, A. Gustafsson, F. Reinhardt, and E. Kapon
Intrasubband and intersubband transitions in lightly and heavily doped GaAs/$Al_xGa_{1-x}As$ multiple quantum wells 12 388
Qin-Sheng Zhu, X. B. Wang, Z. T. Zhong, X. C. Zhou, Y. P. He, Z. P. Cao, G. Z. Zhang, J. Xiao, X. H. Sun, H. Z. Yang, and Q. G. Du
High-resolution surface-sensitive C 1*s* core-level spectra of clean and hydrogen-terminated diamond (100) and (111) surfaces 12 397
R. Graupner, F. Maier, J. Ristein, L. Ley, and Ch. Jung
Compositional ordering in SiGe alloy thin films 12 410
K. L. Whiteaker, I. K. Robinson, J. E. Van Nostrand, and D. G. Cahill
Growth mode in Si(100)-(2×1) epitaxy by low-temperature chemical-vapor deposition 12 421
Perng-Hung Wu and Deng-Sung Lin
Tunable polariton absorption of distributed feedback microcavities at room temperature 12 428
Tohru Fujita, Yoshihiro Sato, Tetsuya Kuitani, and Teruya Ishihara
Oblique roughness replication in strained SiGe/Si multilayers 12 435
V. Holý, A. A. Darhuber, J. Stangl, G. Bauer, J. Nützel, and G. Abstreiter
RHEED intensity oscillations observed during the growth of CaF_2 on Si(111) 12 443
Andrzej Daniluk, Piotr Mazurek, Krzysztof Paprocki, and Paweł Mikołajczak
Path-integral approach to the scattering theory of quantum transport 12 448
D. Endesfelder

Surface physics, low-dimensional systems, and related topics

Tunneling currents and boundary conditions in ballistic-electron-emission microscopy 12 456
Katsuyoshi Kobayashi
Magnetic moments of Ni clusters 12 469
F. Aguilera-Granja, S. Bouarab, M. J. López, A. Vega, J. M. Montejano-Carrizales, M. P. Iñiguez, and J. A. Alonso
Adsorption mechanisms, structures, and growth regimes of an archetypal self-assembling system: Decanethiol on Au(111) 12 476
F. Schreiber, A. Eberhardt, T. Y. B. Leung, P. Schwartz, S. M. Wetterer, D. J. Lavrich, L. Berman, P. Fenter, P. Eisenberger, and G. Scoles

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

H-induced reconstructions on Pd(110) 12 482
V. Ledentu, W. Dong, P. Sautet, G. Kresse, and J. Hafner
Structural model for the Si(100)4×3-In surface phase 12 492
A. V. Zotov, A. A. Saranin, V. G. Lifshits, J.-T. Ryu, O. Kubo, H. Tani, M. Katayama, and K. Oura
Observation of domain structure and coarsening at Cu-Pd alloy vicinal surfaces 12 497
S. Goapper, L. Barbier, B. Salanon, A. Loiseau, and X. Torrelles
Self-assembled islands on strained systems: Control of formation, evolution, and spatial distribution 12 501
C. A. C. Mendonça, M. A. Cotta, E. A. Meneses, and M. M. G. Carvalho
Positron states and annihilation characteristics at the (100), (110), and (111) surfaces of alkali metals 12 506
N. G. Fazleev, J. L. Fry, and A. H. Weiss
Bond-orientational structure and melting signature in krypton physisorbed onto graphite at complete coverage 12 520
M. W. Roth
Epitaxial film growth of the charge-density-wave conductor $Rb_{0.30}MoO_3$ on $SrTiO_3(001)$ 12 530
A. J. Steinfort, H. S. J. van der Zant, A. B. Smits, O. C. Mantel, P. M. L. O. Scholte, and C. Dekker
Low-temperature growth morphology of singular and vicinal Ge(001) 12 536
Joseph E. Van Nostrand, S. Jay Chey, and David G. Cahill
High-resolution LEED profile analysis and diffusion barrier estimation for submonolayer homoepitaxy of Ag/Ag(100) 12 544
L. Bardotti, C. R. Stoldt, C. J. Jenks, M. C. Bartelt, J. W. Evans, and P. A. Thiel
Electronic excitations in alkali-metal overlayers. I. Unreconstructed low-temperature phase of Li/Al 12 550
H. Ishida and A. Liebsch
Electronic excitations in alkali-metal overlayers. II. Effects of substitutional adsorption of Na/Al(001) 12 558
H. Ishida and A. Liebsch
Sputtering of high-energy particles from the Ag{100} surface 12 564
Che-Chen Chang and Jiin-Yun Hsieh
Forward electron emission produced in grazing ion-surface collisions: Dependence on the surface topography 12 573
G. R. Gómez, E. A. Sánchez, and O. Grizzi
O^- formation in grazing scattering from an Al(111) surface 12 579
C. Auth, H. Winter, A. G. Borisov, B. Bahrim, D. Teillet-Billy, and J. P. Gauyacq
Nanomechanical properties of Au (111), (001), and (110) surfaces 12 588
J. D. Kiely and J. E. Houston
Orientational ordering in films of molecular hydrogen on boron nitride: Thick (12-layer) films and bilayer films 12 595
Kiho Kim and N. S. Sullivan
Kinetic-energy functionals studied by surface calculations 12 611
L. Vitos, H. L. Skriver, and J. Kollár

Errata

Erratum: Simple but efficient correlation functional from a model pair-correlation function [Phys. Rev. B **49**, 7874 (1994)] 12 616
Emil I. Proynov and Dennis R. Salahub
Erratum: Self-diffusion of adatoms, dimers, and vacancies on Cu(100) [Phys. Rev. B **56**, 7643 (1997)] 12 617
Ghyslain Boisvert and Laurent J. Lewis
Erratum: Evidence for an enhanced magnetoresistance accompanying a continuous phase transition in semiconducting $La_{0.67}Mg_{0.33}MnO_3$ [Phys. Rev. B **56**, 12 714 (1997)] 12 617
X. Z. Zhou, H. P. Kunkel, J. H. Zhao, P. A. Stampe, and Gwyn Williams

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 19** **15 MAY 1998-I**

Erratum: Full nonlinear closure for a hydrodynamic model of transport in silicon
[Phys. Rev. B **57**, 4456 (1998)] 12 617
M. Trovato and P. Falsaperla

Cumulative Author Index 12 618